- Single-Chip Interface Solution for the 9-terminal GeoPort™ Host (DTE)
- Designed to Operate up to 4 Mbit/s Full Duplex
- Single 5-V Supply Operation
- 6-kV ESD Protection on All Terminals
- Backward compatible With AppleTalk[™] and LocalTalk[™]
- Combines Multiple Components into a Single-chip Solution
- Complements the SN75LBC777 9-Terminal GeoPort Peripheral (DCE) Interface Device
- LinBiCMOS™ Process Technology

(TOP VIEW) DA1 \square 20 ☐ GND 2 19 V_{EE} 3 18 DY1 4 17 TI RY3 C+ □ SHDN [5 16 ☐ RB3 DZ2 \square 6 15 ☐ RA2 DY2 □ 7 14 □ RY2 GND [13 DEN \Box 9 12 ☐ RA1 10 ☐ RY1 DA2 11

DB or DW PACKAGE

description

The SN75LBC776 is a low-power LinBiCMOS device that incorporates the drivers and receivers for a 9-pin GeoPort host interface. GeoPort combines hybrid EIA/TIA-422-B and EIA/TIA-423-B drivers and receivers to transmit data up to four megabits per second (Mbit/s) full duplex. GeoPort is a serial communications standard that is intended to replace the RS-232, Appletalk, and LocalTalk printer ports all in one connector in addition to providing real-time data transfer capability. It provides point-to-point connections between GeoPort-compatible devices with data transmission rates up to 4 Mbit/s full duplex and a hot-plug feature. Applications include connection to telephony, integrated services digital network (ISDN), digital sound and imaging, fax-data modems, and other serial and parallel connections. The GeoPort is backwardly compatible to both LocalTalk and AppleTalk.

While the SN75LBC776 is powered-off (V_{CC} = 0) the outputs are in a high-impedance state. When the shutdown (SHDN) terminal is high, the charge pump is powered down and the outputs are in a high-impedance state. The driver enable (\overline{DEN}) terminal sends the outputs of the differential driver into a high-impedance state with a high input signal. All drivers and receivers have fail-safe mechanisms to ensure a high output state when the inputs are left open.

A switched-capacitor voltage converter generates the negative voltage required from a single 5-V supply using four 0.1- μ F capacitors, two capacitors between the C+ and C- terminals and two capacitors between V_{EE} and ground.

The SN75LBC776 is characterized for operation over the 0°C to 70°C temperature range.



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DRIVER FUNCTION TABLE†

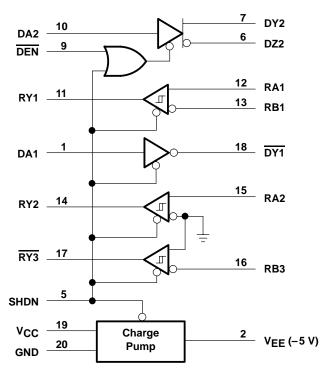
INPUT	INPUT	ENABLE	ENABLE	OUTPUT	OUT	PUT
DA1	DA2	SHDN	DEN	DY1	DY2	DZ2
Н	Х	L	Х	L	Х	Х
L	X	L	Х	Н	Х	Х
X	н	L	L	Х	Н	L
X	L	L	L	Х	L	Н
OPEN	OPEN	L	L	L	Н	L
X	X	Н	Х	Z	Z	Z
Х	X	Х	Н	Х	Z	Z
X	X	OPEN	OPEN	Z	Z	Z

 $^{^{\}dagger}$ H = high level L = low level X = irrelevant ? = indeterminate Z = high impedance (off)

RECEIVER FUNCTION TABLE†

INPUT RA1 RB1	INPUT RA2 & RB3	ENABLE SHDN	OUTPUT RY1	OUTPUT RY2	OUTPUT RY3
H L	Н	L	Н	Н	L
L H	L	L	L	L	Н
OPEN	OPEN	L	Н	Н	Н
SHORT‡	SHORT‡	L	?	?	?
x x	Х	Н	Z	Z	Z
x x	X	OPEN	Z	Z	Z

function logic diagram (positive logic)





absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Positive supply voltage range, V _{CC} (see Note 1)	–0.5 to 7 V
Negative supply voltage range, V _{EE} (see Note 1)	–7 to 0.5 V
Receiver input voltage range (RA, RB)	15 V to 15 V
Receiver differential input voltage range, V _{ID}	12 to 12 V
Receiver output voltage range (RY)	0.5 V to 5.5 V
Driver output voltage range (Power Off) (DY1, DY2, DZ2)	15 V to 15 V
Driver output voltage range (Power On) (DY1, DY2, DZ2)	11 V to 11 V
Driver input voltage range (DA, SHND, DEN)	\dots -0.5 V to V _{CC+} 0.4 V
Continuous total power dissipation	. See Dissipation Rating Table
Continuous total power dissipation Electrostatic discharge (see Note 2): (Bus terminals), Class 3, A	, .
	6 kV
Electrostatic discharge (see Note 2): (Bus terminals), Class 3, A	6 kV
Electrostatic discharge (see Note 2): (Bus terminals), Class 3, A	6 kV
Electrostatic discharge (see Note 2): (Bus terminals), Class 3, A	6 kV
Electrostatic discharge (see Note 2): (Bus terminals), Class 3, A	6 kV 500 V 6 kV 500 V 500 V 500 V 500 V 6 kV 500 V 500 C to 70°C -65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. All voltage values are with respect to network ground terminal unless otherwise noted.

2. This parameter is measured in accordance with MIL-STD-883C, Method 3015.7.

DISSIPATION RATING TABLE

PACKAGE	T _A ≤ 25°C POWER RATING	OPERATING FACTOR ABOVE T _A = 25°C	T _A = 70°C POWER RATING
DB	1035 mW	8.3 mW/°C	660 mW
DW	1125 mW	9.0 mW/°C	720 mW



recommended operating conditions

		MIN	NOM	MAX	UNIT
Supply voltage, V _{CC}		4.75	5	5.25	V
High-level input voltage, VIH	DA, SHDN, DEN	2		5.25	V
Low-level input voltage, V _{IL}	DA, SHDN, DEN			0.8	V
Receiver common-mode input voltage, V _{IC}				7	V
Receiver differential input volta	ge, V _{ID}	-12		12	V
Voltage-converter filter capacit	Voltage-converter filter capacitance				μF
Voltage-converter filter-capacit			0.2	Ω	
Operating free-air temperature	, T _A	0		70	°C

driver electrical characteristics over operating free-air temperature range (unless otherwise noted)

	PARAMETER	TEST CONI	DITIONS	MIN	TYP	MAX	UNIT
Vau	High-level output voltage		R _L = 12 kΩ	3.6	4.53		V
VOH	nigri-level output voltage	Single ended,	$R_L = 120 \Omega$	2	3.63		V
Vai	Low-level output voltage	See Figure 1	$R_L = 12 \text{ k}\Omega$		-4.53	-3.6	V
VOL	Low-level output voltage		$R_L = 120 \Omega$		-2.7	-1.8	V
IVODI	Magnitude of differential output voltage $ (V_{(DY)} - V_{(DZ)} $	R _L = 120 Ω,	See Figure 2	4			٧
Δ V _{OD}	Change in differential voltage magnitude					250	mV
Voc	Common-mode output voltage			-1		3	V
ΔVOC(SS)	Magnitude of change, common-mode steady state output voltage	See Figure 3				200	mV
ΔVOC(PP)	Magnitude of change, common-mode peak-to-peak output voltage				700		mV
	Complex compact	SHDN = DEN = 0 V,	No load		7	15	mA
ICC	Supply current	SHDN = DEN = 5 V,	No load			100	μΑ
loz	High-impedance output current	$V_O = -10 \text{ V to } 10 \text{ V},$	V _{CC} = 0 or 5 V			±100	μΑ
los	Short-circuit output current (see Note 3)	$V_0 = -5 \text{ V to } 5 \text{ V}$			±170	±450	mA

NOTE 3: Not more than one output should be shorted at one time.



driver switching characteristics over operating free-air temperature range (unless otherwise noted)

	PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
tPHL	Propagation delay time, high-to-low level output				42	75	ns
tPLH	Propagation delay time, low-to-high level output				41	75	ns
tPZL	Driver output enable time to low-level output				25	100	μs
^t PZH	Driver output enable time to high-level output	SHDN	Single ended,		25	100	μs
t _{PLZ}	Driver output disable time from low-level output	SHDIN	See Figure 4		28	100	ns
tPHZ	Driver output disable time from high-level output	1			37	100	ns
t _r	Rise time			10	25	75	ns
tf	Fall time			10	23	75	ns
tPHL	Propagation delay time, high-to-low level output				40	75	ns
tPLH	Propagation delay time, low-to-high level output				42	75	ns
4	Driver cutout enable time to leve level cutout	SHDN			25	100	μs
tPZL	Driver output enable time to low-level output	DEN			29	150	ns
	Driver output enable time to high-level output	SHDN			25	100	μs
^t PZH	Driver output enable time to high-level output	DEN	Differential,		35	150	ns
	Driver output disable time from low-level output	SHDN	See Figure 5		28	100	ns
tPLZ	Driver output disable time from low-level output	DEN			34	100	ns
.	Driver output disable time from high level output	SHDN			37	100	ns
^t PHZ	Driver output disable time from high-level output				34	100	ns
t _r	Rise time			10	27	75	ns
tf	Fall time			10	26	75	ns
tSK(p)	Pulse skew, tpLH - tpHL					22	ns

receiver electrical characteristics over operating free-air temperature range (unless otherwise noted)

	PARAMETER	•	TEST CONDITIO	NS	MIN	TYP	MAX	UNIT
V _{IT+}	Positive-going input threshold voltage						200	mV
VIT-	Negative-going input threshold voltage	See Figure 6			-200			IIIV
V _{hys}	Differential input voltage hysteresis ($V_{IT+} - V_{IT-}$)					50		mV
Vон	High-level output voltage (see Note 4)	$V_{IC} = 0$,	$I_{OH} = -2 \text{ mA},$	See Figure 6	2	4.9		V
VOL	Low-level output voltage	$V_{IC} = 0$,	$I_{OL} = 2 \text{ mA},$	See Figure 6		0.2	0.8	V
laa	Short circuit output current	V _O = 0			-85	-45		mA
ios	IOS Short-circuit output current		VO = VCC			47	+85	IIIA
RĮ	Input resistance	V _{CC} = 0 or 5.25 V, V _I = -12 V to 12 V			6	30		kΩ

NOTE 4: When the inputs are left unconnected, receivers one and two interpret these as high-level inputs and receiver three interprets these as low-level inputs so that all outputs are at a high level.



receiver switching characteristics over operating free-air temperature range (unless otherwise noted)

	PARAMETER	TEST C	ONDITIONS	MIN	TYP	MAX	UNIT
^t PHL	Propagation delay time, high-to-low-level output				31	75	ns
^t PLH	Propagation delay time, low-to-high level output	1			30	75	ns
t _r	Rise time	$R_L = 2 k\Omega$, See Figure 6	$C_L = 15 pF$,		15	30	ns
t _f	Fall time	See Figure 6			15	30	ns
tSK(P)	Pulse skew tpLH-tpHL	1				20	ns
tPZL	Receiver output enable time to low level output				35	100	ns
^t PZH	Receiver output enable time to high level output	Differential,	Differential, C _L =50 pF,		32	100	ns
^t PLZ	Receiver output disable time from low level output	See Figure 7	_ , ,		21	100	ns
^t PHZ	Receiver output disable time from high level output	1			21	100	ns
^t PZL	Receiver output enable time to low level output				12	25	μs
^t PZH	Receiver output enable time to high level output	Single ended,	$C_L = 50 pF$,		12	25	μs
^t PLZ	Receiver output disable time from low level output	See Figure 7			25	100	ns
^t PHZ	Receiver output disable time from high level output	1			125	400	ns



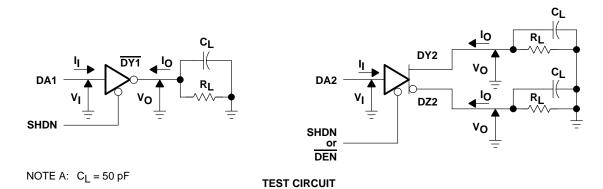


Figure 1. Single-Ended Driver DC Parameter Test

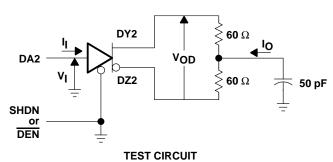
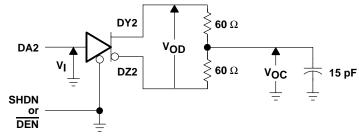
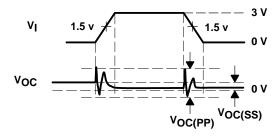


Figure 2. Differential Driver DC Parameter Test



TEST CIRCUIT (see Note A)

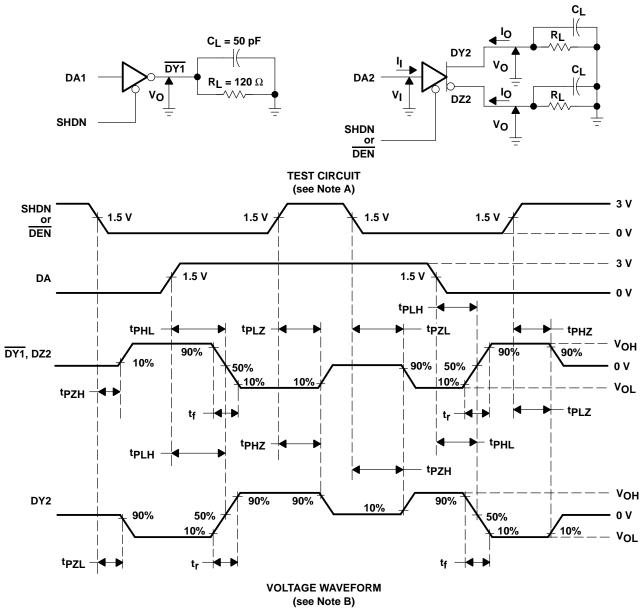


VOLTAGE WAVEFORM

NOTE A: Measured 3dB bandwidth = 300 MHz

Figure 3. Differential-Driver Common-Mode Output Voltage Tests



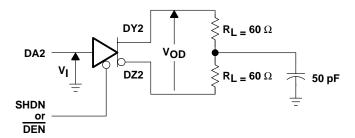


NOTES: A. $C_L = 50 \text{ pF}$, $R_L = 120 \Omega$

B. The input waveform t_r , $t_f \le 10$ ns.

Figure 4. Single-Ended Driver Propagation and Transition Times





TEST CIRCUIT

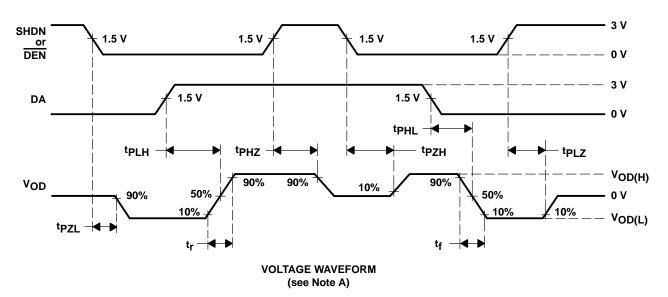


Figure 5. Differential Driver Propagation and Transition Times

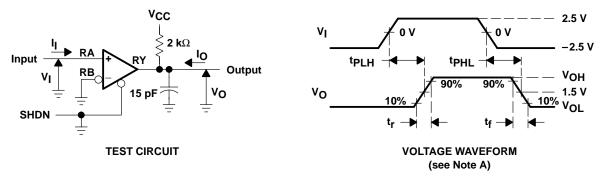
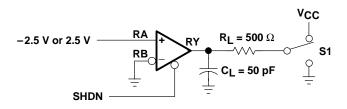


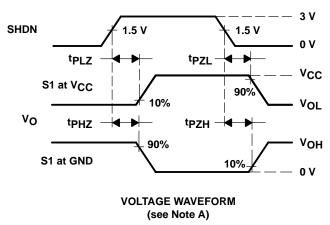
Figure 6. Receiver Propagation and Transition Times

NOTE A: The input waveform t_r , $t_f \le 10$ ns.





TEST CIRCUIT

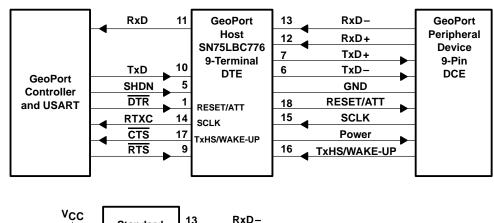


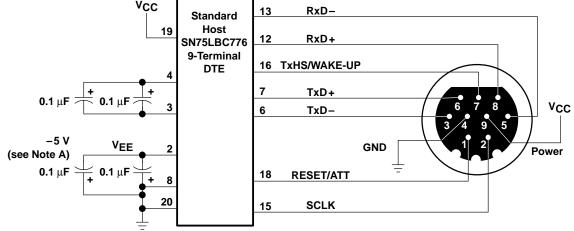
NOTE A: The input waveform t_f , $t_f \le 10$ ns.

Figure 7. Receiver Enable and Disable Test Circuit and Waveforms



APPLICATION INFORMATION





NOTE A: The AVX 0603YC104MATXA or equivalent is one of the possible capacitors that can be used as the charge pump capacitor.

Figure 8. GeoPort 9-Terminal DTE Connection Application

APPLICATION INFORMATION

generator characteristics

	DADAMETED	TEST CONDITIONS	EIA/TIA-	232/V.28	EIA/TIA-	423/V.10	562		UNIT
	PARAMETER	TEST CONDITIONS	MIN	MAX	MIN	MAX	MIN	MAX	UNII
	Output voltage magnitude	Open circuit		25	4	6		13.2	V
$ V_O $		$3 \text{ k}\Omega \leq R_L \leq 7 \text{ k}\Omega$	5	15	NA		3.7		V
		$R_L = 450 \Omega$	NA		3.6		NA		V
V _O (RING)	Output voltage ringing		NA			10%		5%	
los	Short-circuit output current	VO = 0		100		150		60	mA
1	Dower off output ourrent	V _{CC} = 0, V _O < 2 V	300		NA		300		Ω
lO(OFF)	Power-off output current	V _{CC} = 0, V _O < 6 V	NA			±100	NA		μΑ
SR	Output voltage slew rate			30	NA		4	30	V/μs
		±3.3 V to ±3.3 V	NA		NA		0.22	2.1	μs
t _t	Transition time	±3 V to ±3 V		0.04	NA		NA		ui†
		10% to 90%	NA			0.3	NA		ui†

[†] ui is the unit interval and is the inverse of the signaling rate (bit transmit time).

receiver characteristics

	PARAMETER	TEST CONDITIONS	EIA/TIA-232/V.28		EIA/TIA-423/V.10		562		UNIT
	PARAMETER	TEST CONDITIONS	MIN	MAX	MIN	MAX	MIN	MAX	UNIT
$ V_I $	Input voltage magnitude			25		10		25	V
V land to the mark and	Input voltage threehold	V _I < 15 V	-3	3	NA		-3	3	V
VIT	Input voltage threshold	V _I < 10 V	NA		-0.2	0.2	NA		V
Rı	Input resistance	3 V < V _I < 15 V	3	7	NA		3	7	kΩ
K	input resistance	V _I < 10 V	NA		4		NA		kΩ

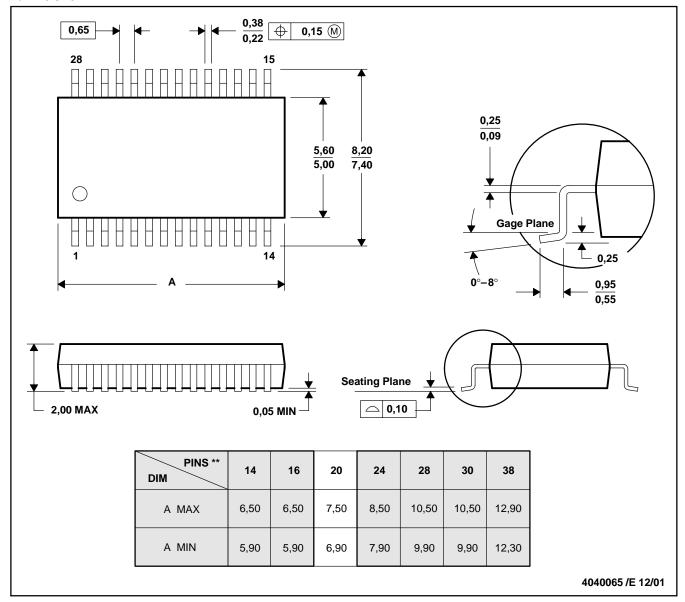


MECHANICAL INFORMATION

DB (R-PDSO-G**)

PLASTIC SMALL-OUTLINE

28 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.

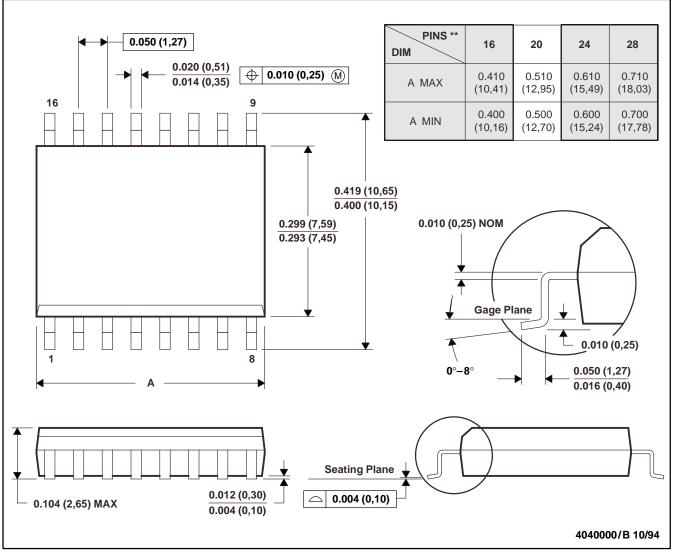
D. Falls within JEDEC MO-150

MECHANICAL INFORMATION

DW (R-PDSO-G**)

PLASTIC SMALL-OUTLINE PACKAGE

16 PIN SHOWN



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MS-013







i.com 8-Jan-2007

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
SN75LBC776DBR	ACTIVE	SSOP	DB	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75LBC776DBRG4	ACTIVE	SSOP	DB	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75LBC776DW	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75LBC776DWG4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75LBC776DWR	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75LBC776DWRG4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device		Package Drawing			Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN75LBC776DBR	SSOP	DB	20	2000	330.0	16.4	8.2	7.5	2.5	12.0	16.0	Q1
SN75LBC776DWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.1	2.65	12.0	24.0	Q1





*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN75LBC776DBR	SSOP	DB	20	2000	346.0	346.0	33.0
SN75LBC776DWR	SOIC	DW	20	2000	346.0	346.0	41.0

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